

## BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz



### Typical Applications

The HMC686LP4(E) is Ideal for:

- Cellular/3G & LTE/WiMAX/4G
- Basestations & Repeaters
- GSM, CDMA & OFDM
- Transmitters and Receivers

### Features

- High Input IP3: +34 dBm
- 7.5 dB Conversion Loss @ 0 dBm LO
- Optimized to High Side LO Input for 0.7 - 1.1 GHz RF Band
- Optimized to Low Side LO Input for 1.4 - 1.5 GHz RF Band
- Adjustable Supply Current
- 24 Lead 4x4mm SMT Package: 16mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC686LP4(E) is a high dynamic range passive MMIC mixer with integrated LO amplifier in a 4x4 SMT QFN package covering 0.7 to 1.1 GHz. Excellent input IP3 performance of +34 dBm for down conversion is provided for 3G & 4G GSM/CDMA applications at an LO drive of 0 dBm. With an input 1 dB compression of +25 dBm, the RF port will accept a wide range of input signal levels. Conversion loss is 7.5 dB typical. The DC to 500 MHz IF frequency response will satisfy GSM/CDMA transmit or receive frequency plans. The HMC686LP4(E) is optimized to high side LO frequency plans for 0.7 - 1.1 GHz RF Band and is pin for pin compatible with the HMC684LP4(E) which is a 0.7 - 1.0 GHz converter optimized for low side LO. The HMC686LP4(E) is optimized to low side LO frequency plans for 1.4 - 1.5 GHz RF LTE band applications.

### Electrical Specifications, $T_A = +25^\circ C$ , LO = 0 dBm, Vcc1, 2, 3, = +5V

| Nominal Supply                       | I <sub>cc</sub> = 105 mA [1] |      |      | I <sub>cc</sub> = 80 mA [1] | I <sub>cc</sub> = 60 mA [1] | I <sub>cc</sub> = 120mA [2] |      |      | Units |
|--------------------------------------|------------------------------|------|------|-----------------------------|-----------------------------|-----------------------------|------|------|-------|
|                                      | Min.                         | Typ. | Max. | Typ.                        | Typ.                        | Min.                        | Typ. | Max. |       |
| Frequency Range, RF                  | 0.7 - 1.1                    |      |      |                             |                             | 1.4 - 1.5                   |      |      | GHz   |
| Frequency Range, LO                  | 0.85 - 1.25                  |      |      |                             |                             | 1.1 - 1.5                   |      |      | GHz   |
| LO Injection Type                    | High Side                    |      |      |                             |                             | Low Side                    |      |      |       |
| Frequency Range, IF                  | DC to 500                    |      |      |                             |                             | 50 - 250                    |      |      | MHz   |
| Conversion Loss                      |                              | 7.5  | 9.5  | 7.5                         | 7.5                         |                             | 8    | 10   | dB    |
| Noise Figure (SSB)                   |                              | 7.5  |      | 7.5                         | 7.5                         |                             | 8    |      | dB    |
| LO to RF Isolation                   | 18                           | 24   |      | 26                          | 28                          | 20                          | 36   |      | dB    |
| LO to IF Isolation                   | 30                           | 41   |      | 41                          | 42                          | 28                          | 39   |      | dB    |
| RF to IF Isolation                   | 27                           | 36   |      | 36                          | 35                          | 27                          | 38   |      | dB    |
| IP3 (Input)                          |                              | 34   |      | 32.5                        | 31.5                        |                             | 32   |      | dBm   |
| 1 dB Compression (Input)             |                              | 25   |      | 24.5                        | 23.5                        |                             | 25   |      | dBm   |
| LO Drive Input Level (Typical)       | -3 to +3                     |      |      | -3 to +3                    | -3 to +3                    | -3 to +3                    |      |      | dBm   |
| Gate Bias Voltage G_BIAS             | 3.5                          |      |      | 3.5                         | 3.5                         | 2.5                         |      |      | V     |
| Supply Current I <sub>cc</sub> Total |                              | 105  | 125  | 80                          | 60                          |                             | 120  | 140  | mA    |

[1] Unless otherwise noted all measurements performed for 0.7 - 1.1 GHz RF band as downconverter with high side LO & IF = 150 MHz, I<sub>cc</sub> = 105 mA, G\_Bias = 3.5 V

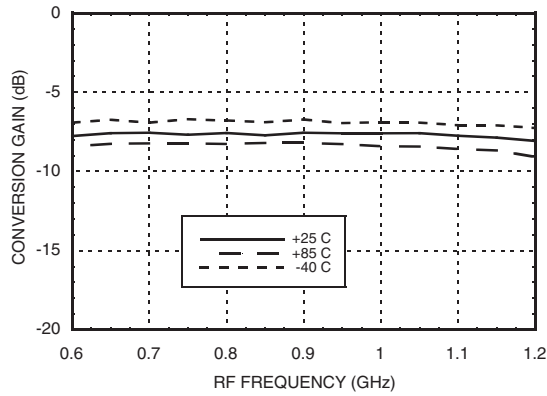
[2] Unless otherwise noted all measurements performed for 1.4 - 1.5 GHz RF LTE band as downconverter with low side LO & IF = 140 MHz

**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**



**0.7 - 1.1 GHz RF Band Performance**

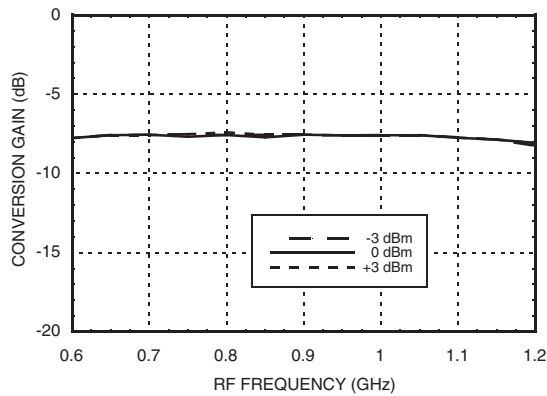
**Conversion Gain vs. Temperature**



**Isolation**



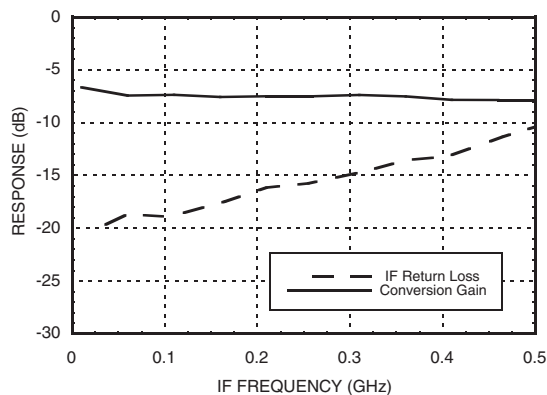
**Conversion Gain vs. LO Drive**



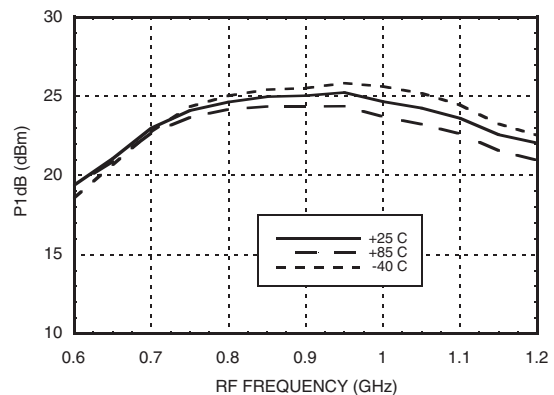
**Return Loss**



**IF Bandwidth (LO = 1.1 GHz)**



**Input P1dB vs. Temperature**



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

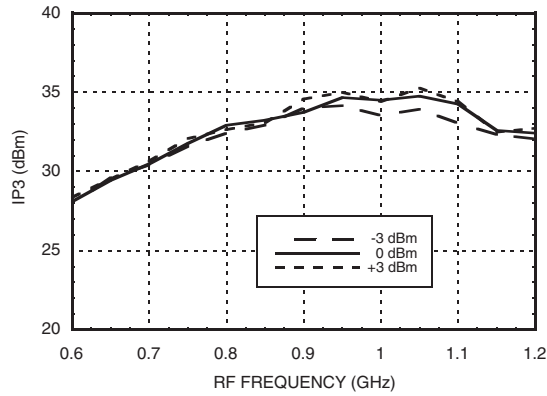
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



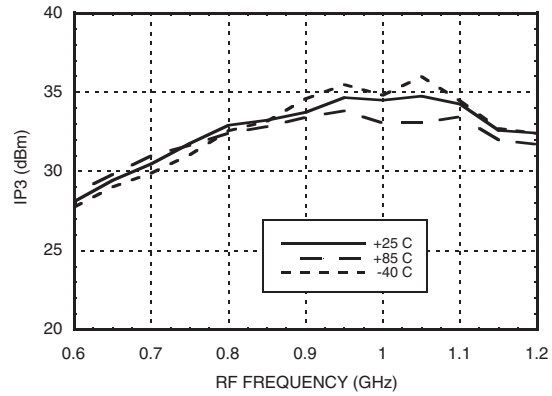
**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**

**0.7 - 1.1 GHz RF Band Performance**

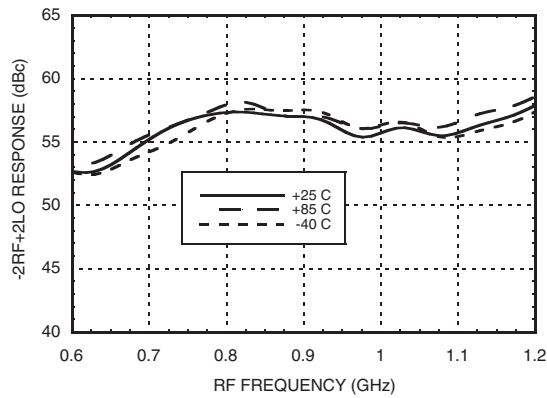
**Input IP3 vs. LO Drive <sup>[1]</sup>**



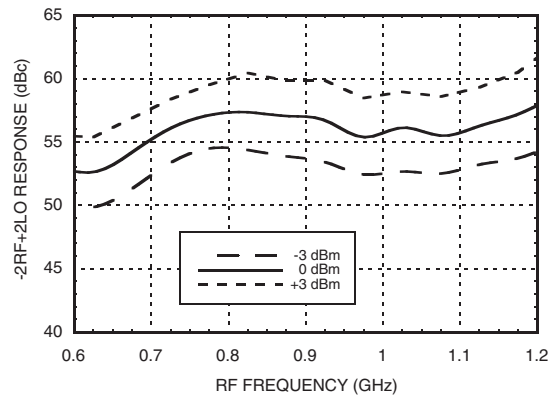
**Input IP3 vs. Temperature <sup>[1]</sup>**



**-2RF +2LO Response vs. Temperature <sup>[2]</sup>**



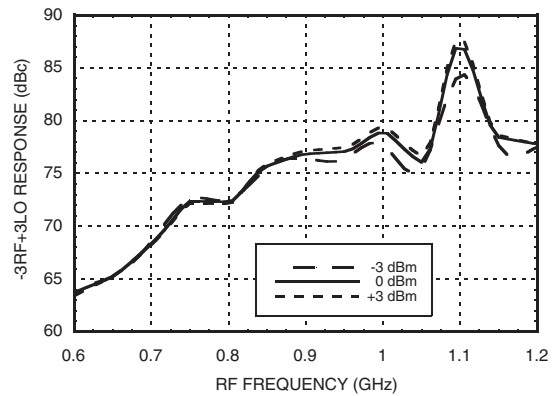
**-2RF +2LO Response vs. LO Drive <sup>[2]</sup>**



**-3RF +3LO Response vs. Temperature <sup>[2]</sup>**



**-3RF +3LO Response vs. LO Drive <sup>[2]</sup>**



[1] Two-tone input power = +9 dBm each tone, 1 MHz spacing. [2] Referenced to RF Input power at 0 dBm

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



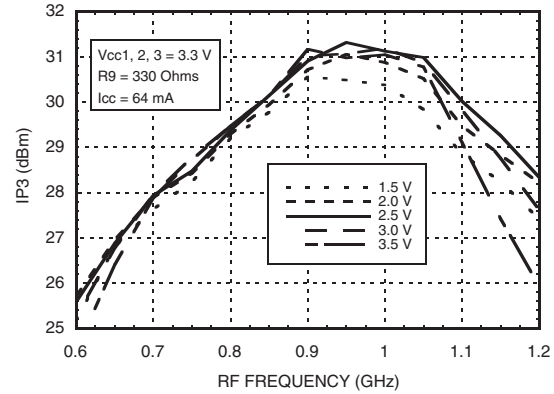
**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**

**0.7 - 1.1 GHz RF Band Performance for Low Power Consumption**

**Conversion Gain vs. G\_Bias Voltage**



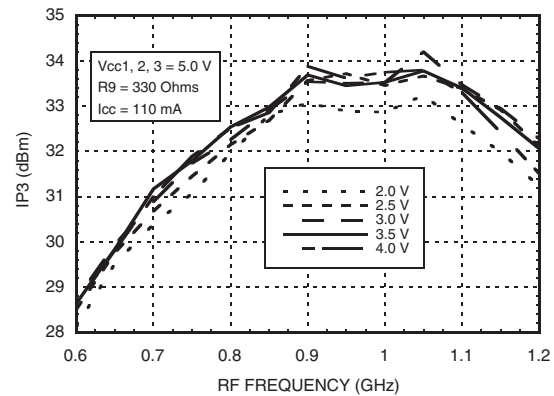
**Input IP3 vs. G\_Bias Voltage [1]**



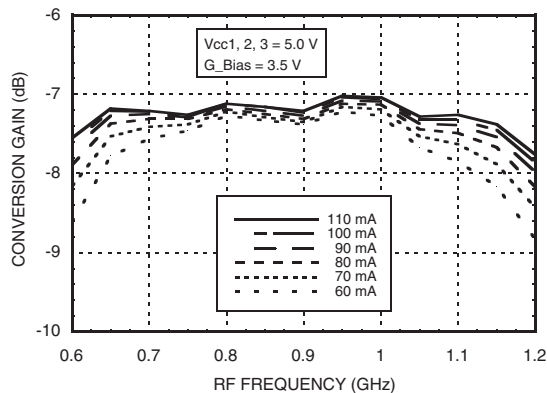
**Conversion Gain vs. G\_Bias Voltage**



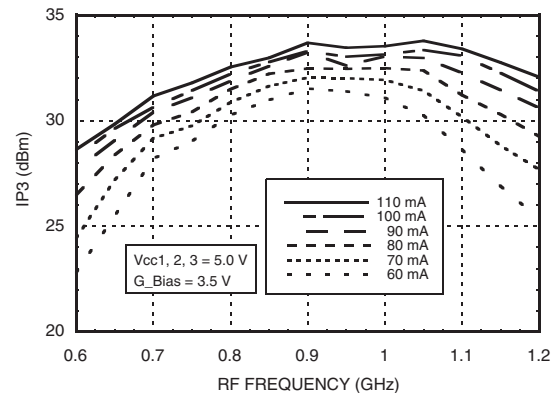
**Input IP3 vs. G\_Bias Voltage [1]**



**Conversion Gain vs. Icc**



**Input IP3 vs. Icc [1]**



[1] Two-tone input power = +9 dBm each tone, 1 MHz spacing

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

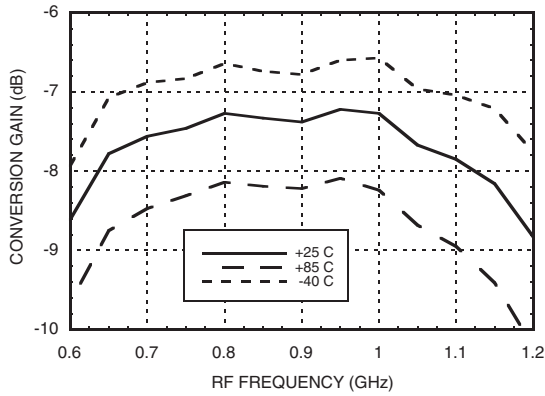
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



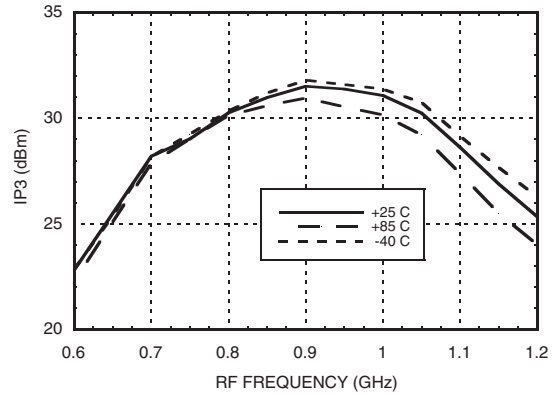
**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**

**0.7 - 1.1 GHz RF Band Performance for Low Power Consumption**

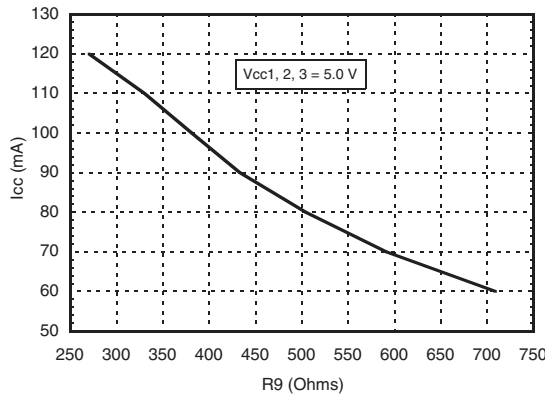
**Conversion Gain vs. Temperature,  $I_{cc} = 60 \text{ mA}$**



**Input IP3 vs. Temperature,  $I_{cc} = 60 \text{ mA}$  [1]**

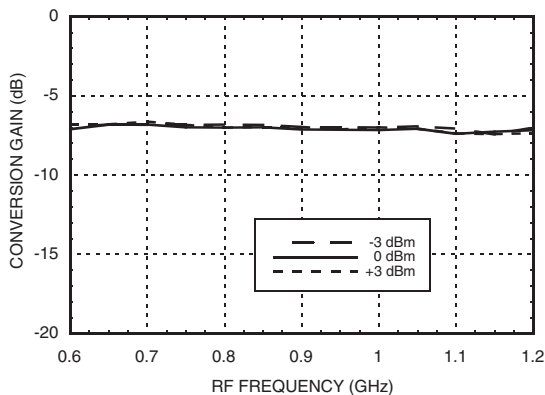


**$I_{cc}$  vs.  $R_9$**

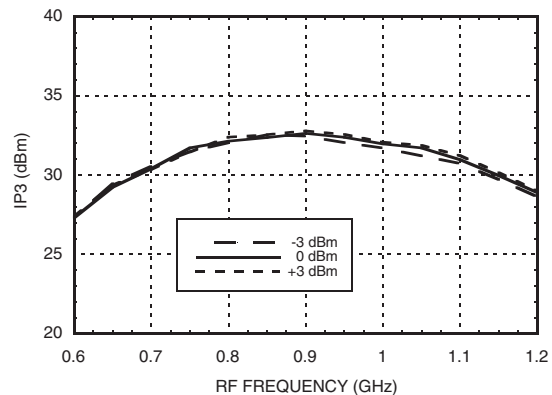


**Typical Upconverter Performance**

**Conversion Gain vs. LO Drive**



**Input IP3 vs. LO Drive [1]**



[1] Two-tone input power = +9 dBm each tone, 1 MHz spacing

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

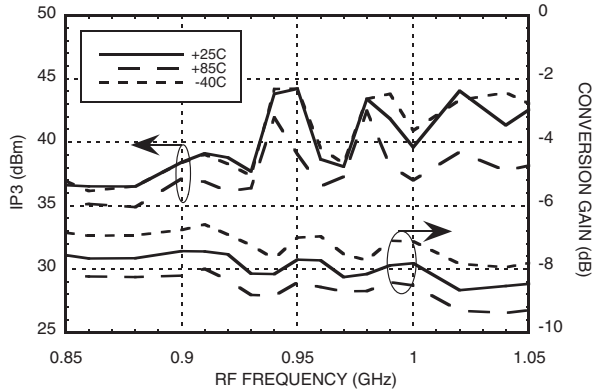
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



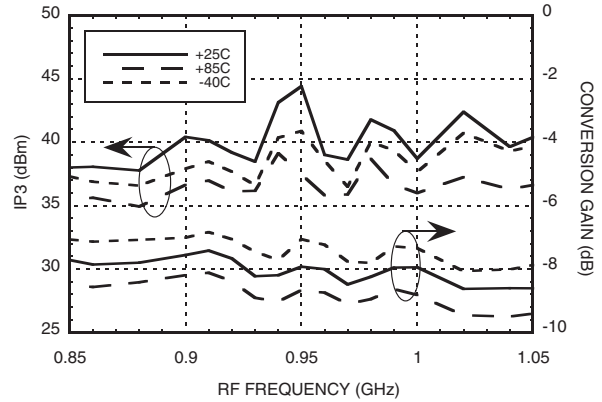
**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**

**0.7 - 1.1 GHz RF Band Performance for Narrowband High IP3 Upconverter Tune [1]**

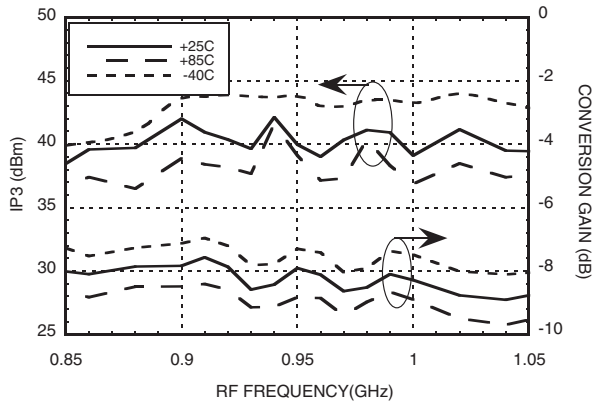
**Conversion Gain and IP3, G\_BIAS = 1.5 [2][3]**



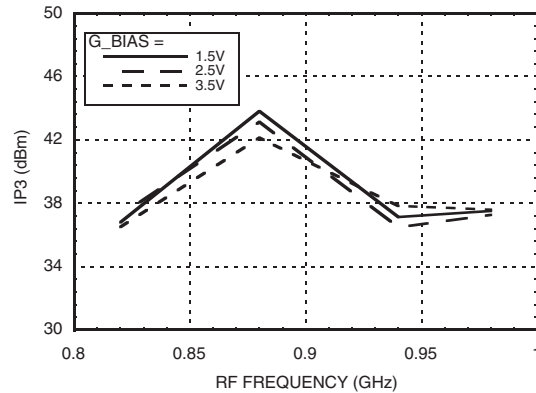
**Conversion Gain and IP3, G\_BIAS = 2.5 [2][3]**



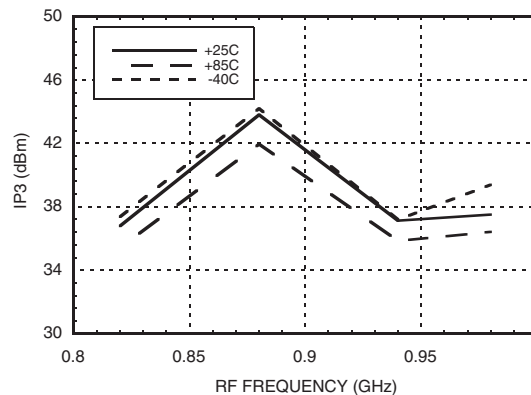
**Conversion Gain and IP3, G\_BIAS = 3.5 [2][3]**



**IP3 vs G\_BIAS, LO = 1060 MHz [2]**



**IP3 vs Temperature, G\_BIAS = 1.5V, LO = 1060 MHz [2]**



[1] See Narrowband High IP3 Upconverter Tune Evaluation PCB and schematic.

[2] Two-tone input power = +9 dBm each tone, 1 MHz spacing.

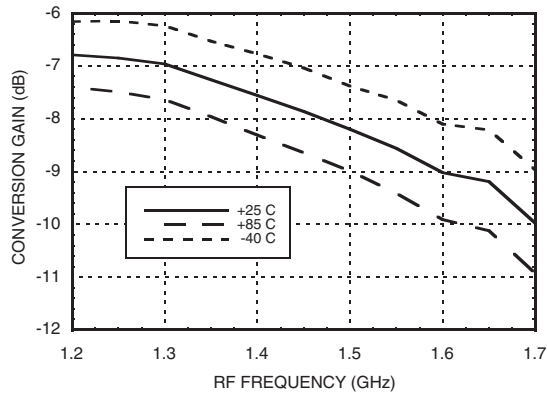
[3] IF = 120 MHz



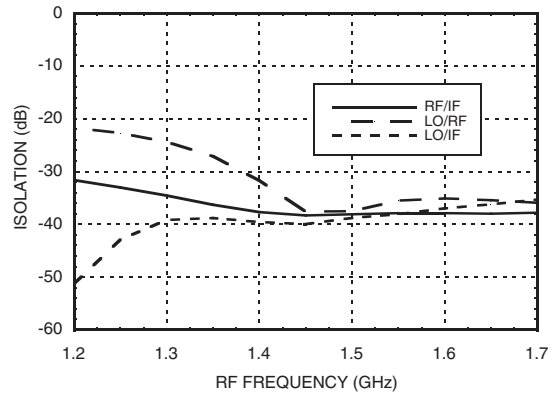
**BiCMOS MIXER W/ INTEGRATED  
LO AMPLIFIER, 700 - 1500 MHz**

**1.4 - 1.5 GHz RF LTE Band Performance [1]**

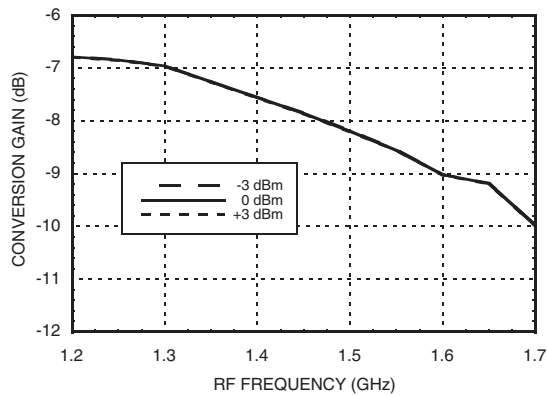
**Conversion Gain vs. Temperature [2]**



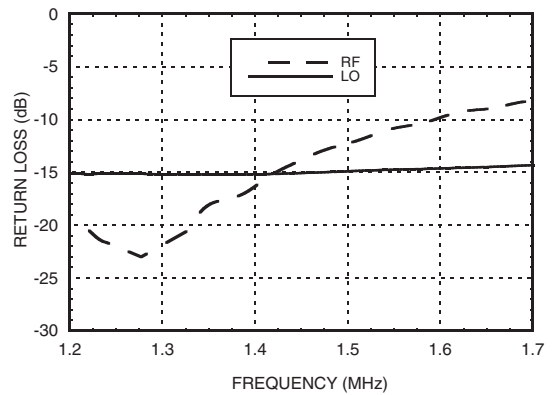
**Isolation [2]**



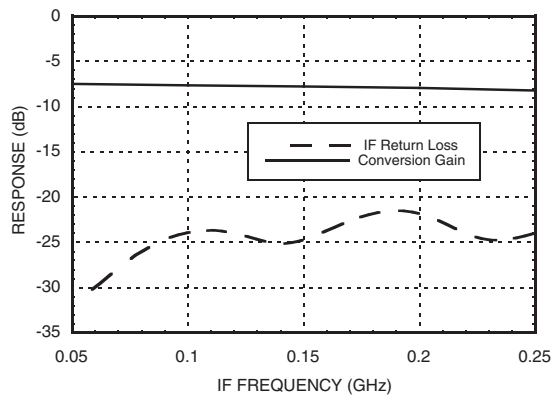
**Conversion Gain vs. LO Drive [2]**



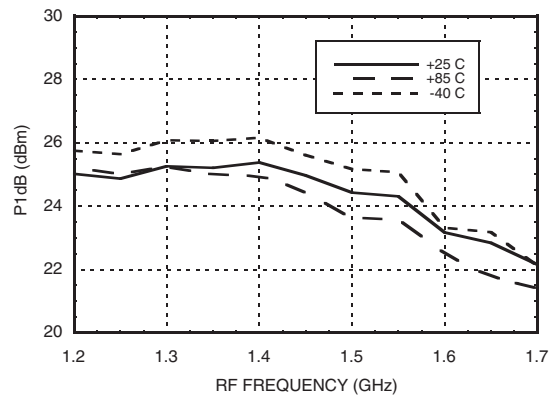
**Return Loss**



**IF Bandwidth (LO = 1.3 GHz)**



**Input P1dB vs. Temperature [2]**



[1] See 1.4 - 1.5 GHz RF LTE Band Evaluation PCB and schematic.

[2] G\_Bias = +2.5V, IF = 140 MHz

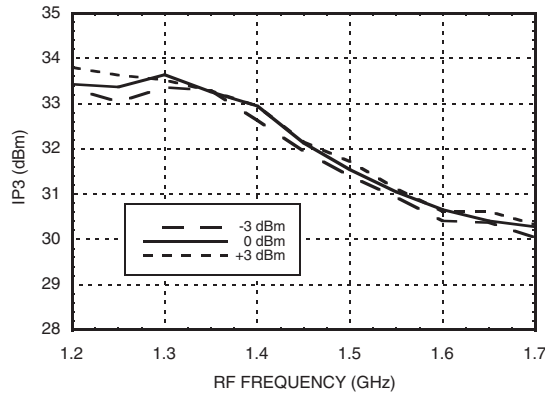
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



### 1.4 - 1.5 GHz RF LTE Band Performance [1]

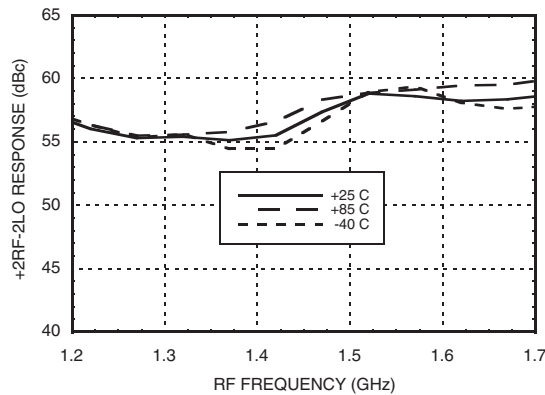
**Input IP3 vs. LO Drive [2] [3]**



**Input IP3 vs. Temperature [2] [3]**



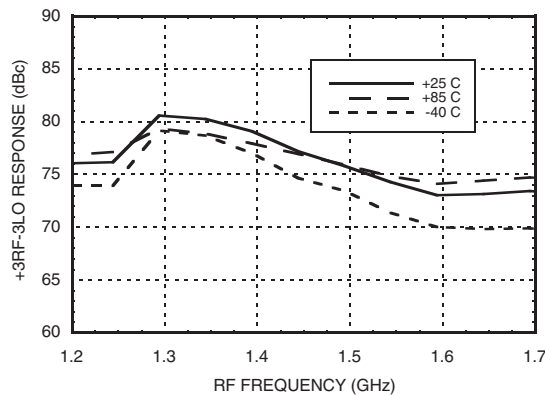
**+2RF -2LO Response vs. Temperature [2] [4]**



**+2RF -2LO Response vs. LO Drive [2] [4]**



**+3RF -3LO Response vs. Temperature [2] [4]**



**+3RF -3LO Response vs. LO Drive [2] [4]**



[1] See 1.4 - 1.5 GHz RF LTE Band Evaluation PCB and schematic.

[2] G\_Bias = +2.5V, IF = 140 MHz

[3] Two-tone input power = +9 dBm each tone, 1 MHz spacing

[4] Referenced to RF Input Power at 0 dBm

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D





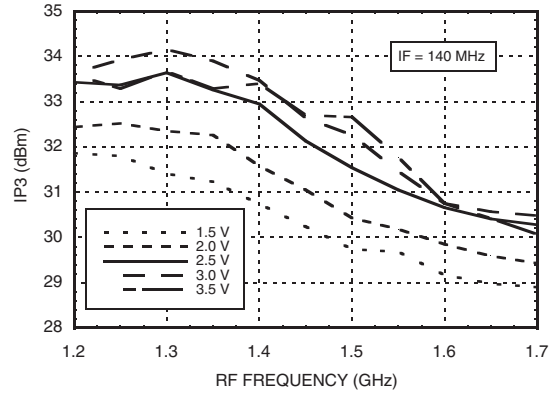
**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**

**1.4 - 1.5 GHz RF LTE Band Performance [1]**

**Conversion Gain vs. G\_Bias Voltage**



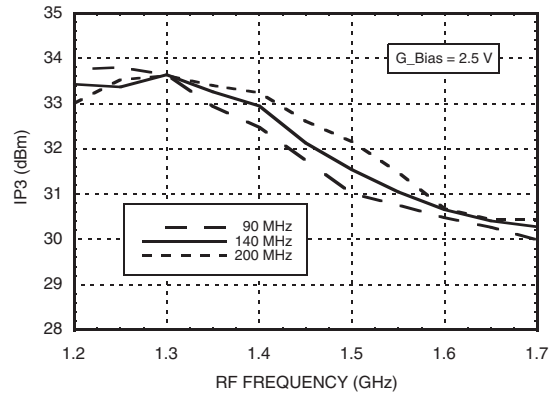
**Input IP3 vs. G\_Bias Voltage [2]**



**Conversion Gain vs. IF Frequency**



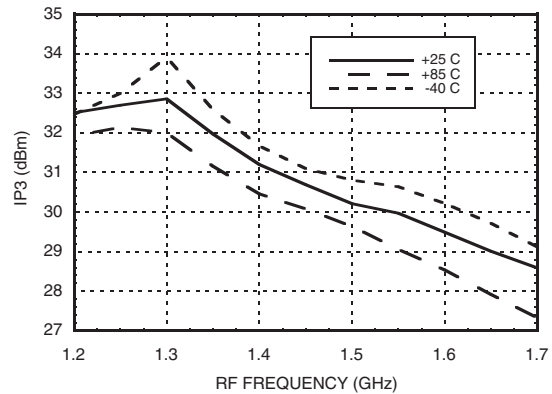
**Input IP3 vs. IF Frequency [2]**



**Upconverter Performance Conversion Gain vs. Temperature [3]**



**Upconverter Performance Input IP3 vs. Temperature [2] [3]**



[1] See 1.4 - 1.5 GHz RF LTE Band Evaluation PCB and schematic.

[3] G\_Bias = +2.5V, IF = 140 MHz

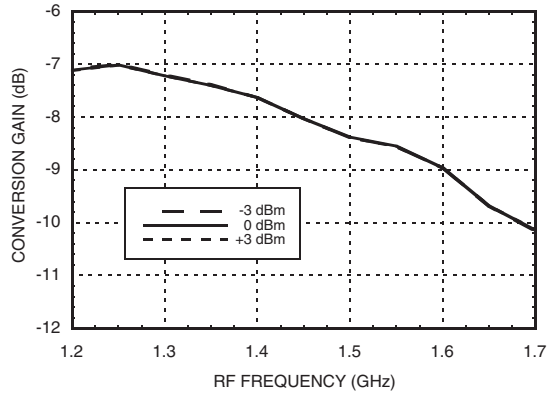
[2] Two-tone input power = +9 dBm each tone, 1 MHz spacing

## BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz

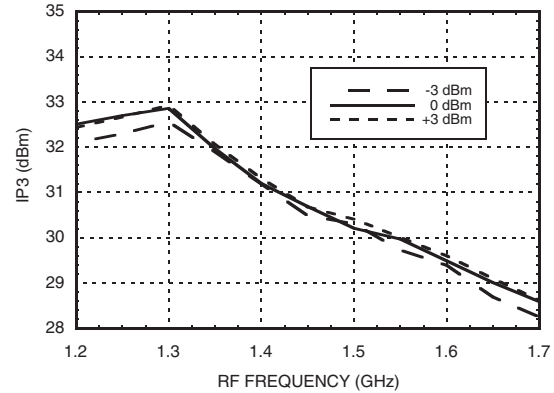


### 1.4 - 1.5 GHz RF LTE Band Performance [1]

**Upconverter Performance  
Conversion Gain vs. LO Drive [2]**



**Upconverter Performance  
Input IP3 vs. LO Drive [2] [3]**



**Harmonics of LO [4]**

| LO Freq. (GHz) | nLO Spur @ RF Port |    |    |    |
|----------------|--------------------|----|----|----|
|                | 1                  | 2  | 3  | 4  |
| 0.75           | 28                 | 40 | 40 | 39 |
| 0.85           | 25                 | 34 | 60 | 33 |
| 0.95           | 23                 | 29 | 32 | 31 |
| 1.05           | 23                 | 28 | 36 | 26 |
| 1.15           | 26                 | 23 | 38 | 34 |
| 1.25           | 33                 | 19 | 44 | 34 |
| 1.35           | 39                 | 18 | 39 | 38 |

LO = 0 dBm  
All values in dBc below input LO level measured at RF port

**MxN Spurious @ IF Port [4]**

| mRF | nLO |    |    |    |    |
|-----|-----|----|----|----|----|
|     | 0   | 1  | 2  | 3  | 4  |
| 0   | xx  | 41 | 17 | 31 | 40 |
| 1   | 26  | 0  | 28 | 17 | 46 |
| 2   | 52  | 50 | 50 | 62 | 58 |
| 3   | 80  | 66 | 87 | 71 | 87 |
| 4   | 98  | 97 | 98 | 97 | 98 |

RF Freq. = 0.9 GHz @ 0 dBm  
LO Freq. = 1.0 GHz @ 0 dBm  
All values in dBc below IF power level (-1RF + 1LO).

### Absolute Maximum Ratings

|   |               |
|---|---------------|
| RF / IF Input (Vcc1,2,3 = +5V)                              | +23 dBm       |
| LO Drive (Vcc1,2,3 = +5V)                                   | +10 dBm       |
| Vcc1,2,3  | +5.5V         |
| Channel Temperature   | 125 °C        |
| Continuous Pdiss (T = 85°C)<br>(derate 19 mW/°C above 85°C) | 0.76 W        |
| Thermal Resistance<br>(channel to ground paddle)            | 52 °C/W       |
| Storage Temperature   | -65 to 150 °C |
| Operating Temperature                                       | -40 to +85 °C |

### Typical Supply Current vs. Vcc

| Vcc1,2,3 (V) | Icc Total (mA) |
|--------------|----------------|
| 4.75         | 100            |
| 5.00         | 105            |
| 5.25         | 110            |

Product will operate over full voltage range shown above.



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

[1] See 1.4 - 1.5 GHz RF LTE Band Evaluation PCB and schematic.

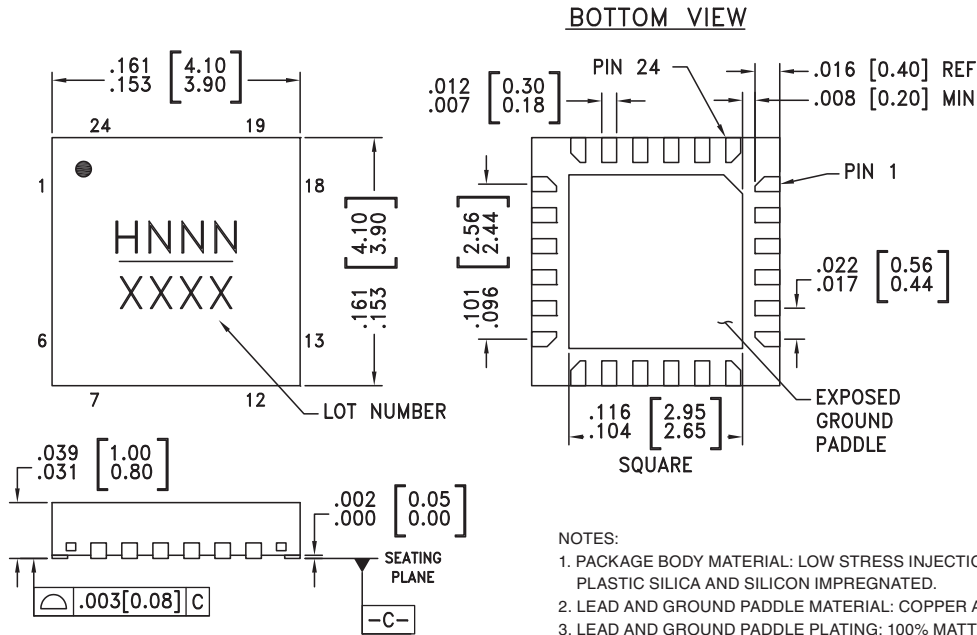
[2] G\_Bias = +2.5V, IF = 140 MHz

[3] Two-tone input power = +9 dBm each tone, 1 MHz spacing

[4] See 0.7 - 1.1 GHz RF Band Evaluation PCB and schematic



### Outline Drawing



**NOTES:**


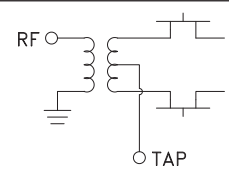
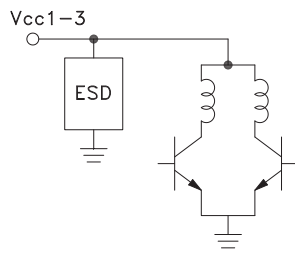
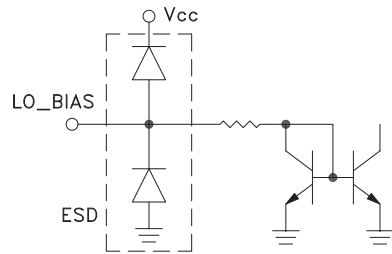
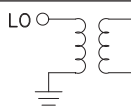
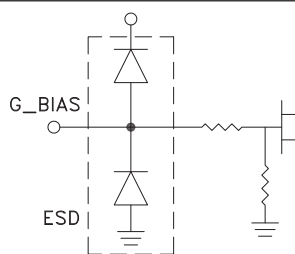
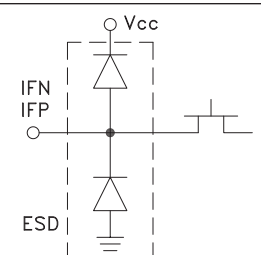
1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY.
3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.
4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
6. PAD BURR LENGTH SHALL BE 0.15mm MAX. PAD BURR HEIGHT SHALL BE 0.25mm MAX.
7. PACKAGE WARP SHALL NOT EXCEED 0.05mm
8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
9. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

### Package Information

| Part Number | Package Body Material                              | Lead Finish   | MSL Rating          | Package Marking <sup>[3]</sup> |
|-------------|--|---------------|---------------------|--------------------------------|
| HMC686LP4   | Low Stress Injection Molded Plastic                | Sn/Pb Solder  | MSL1 <sup>[1]</sup> | H686<br>XXXX                   |
| HMC686LP4E  | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 <sup>[2]</sup> | H686<br>XXXX                   |

[1] Max peak reflow temperature of 235 °C  
 [2] Max peak reflow temperature of 260 °C  
 [3] 4-Digit lot number XXXX

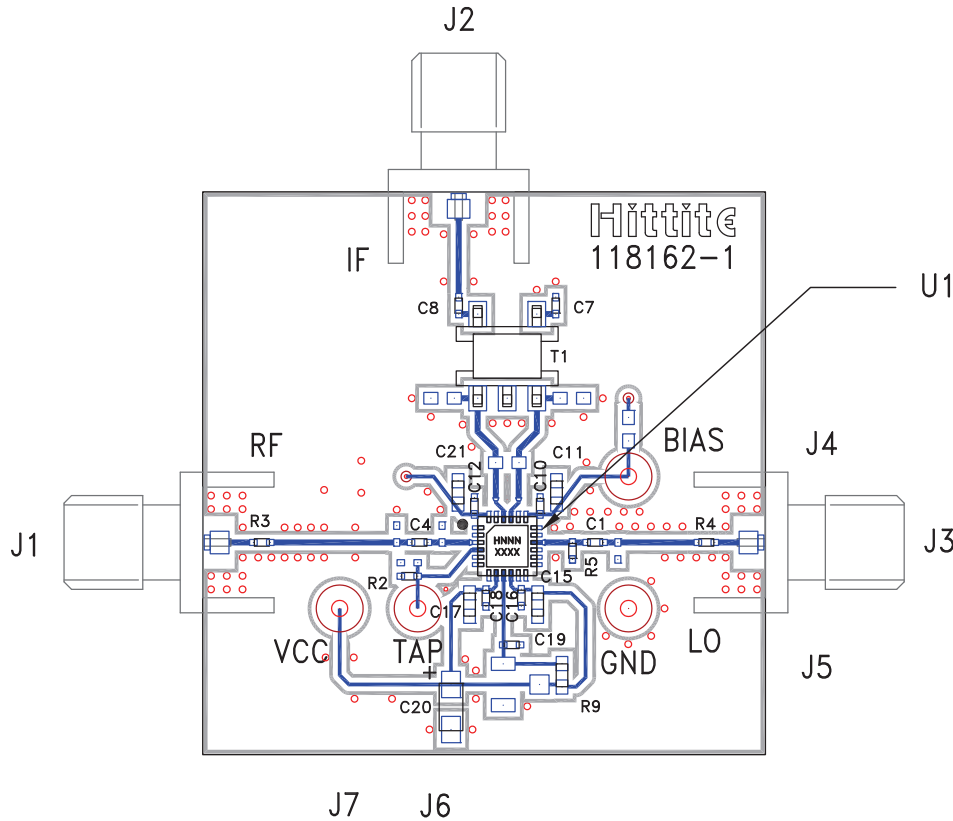

**Pin Descriptions**

| Pin Number                   | Function         | Description   | Interface Schematic   |
|------------------------------|------------------|---|---|
| 1, 6, 7, 11 - 14, 18, 20, 23 | N/C              | No connection. These pins may be connected to RF ground. Performance will not be affected.  |   |
| 2, 5, 15, 17                 | GND              | Package bottom must be connected to RF/DC ground.   |    |
| 3                            | RF               | This pin is matched single-ended to 50 Ohms and DC shorted to ground through a balun.   |    |
| 4                            | TAP              | Center tap of secondary side of the internal RF balun. Short to ground with zero ohms close to the package.   |   |
| 8, 10, 24                    | Vcc1, Vcc2, Vcc3 | Power supply voltage. See application circuit for required external components.   |   |
| 9                            | LO_BIAS          | LO buffer current adjustment pin. Adjust the LO buffer current through the external resistor R9 shown in the application circuit (connect 330 Ohms for nominal operation). This adjustment allows for a trade-off between power dissipation and linearity performance of the converter.   |  |
| 16                           | LO               | This pin is matched single-ended to 50 Ohms and DC shorted to ground through a balun.   |  |
| 19                           | G_BIAS           | External bias. See application circuit for recommended external components. Apply +3.5V for nominal operation at 5V supply voltage. G_Bias can be set to between 0 and 5Vdc. The G_bias pin has an internal 15K ohm resistance to ground. This adjustment allows for a trade off between conversion loss and linearity performance of the converter (see figures CG, IP3 vs. G-Bias). |  |
| 21, 22                       | IFN, IFP         | Differential IF input / output pins matched to differential 50 Ohms. For applications not requiring operation to DC an off chip DC blocking capacitor should be used.   |  |

**BiCMOS MIXER W/ INTEGRATED  
LO AMPLIFIER, 700 - 1500 MHz**



**Evaluation PCB - 0.7 - 1.1 GHz RF Band**



**List of Materials for Evaluation PCB 119936 [1]**

| Item               | Description                       |
|--------------------|-----------------------------------|
| J1 - J3            | SMA Connector                     |
| J4 - J7            | DC Pin                            |
| C1, C19            | 22 pF Capacitor, 0402 Pkg.        |
| C4                 | 6.8 pF Capacitor, 0402 Pkg.       |
| C7, C8             | 10 nF Capacitor, 0402 Pkg.        |
| C10, C12, C16, C18 | 1 nF Capacitor, 0402 Pkg.         |
| C11, C15, C17, C21 | 0.1 μF Capacitor, 0603 Pkg.       |
| C20                | 4.7 μF Case A, Tantalum           |
| R2 - R4            | 0 Ohm Resistor, 0402 Pkg.         |
| R5                 | 68 Ohm Resistor, 0402 Pkg.        |
| R9                 | 330 Ohm Resistor, 0603 Pkg.       |
| T1                 | 1:1 Transformer - Tyco MABACT0039 |
| U1                 | HMC686LP4(E) Downconverter        |
| PCB [2]            | 118162 Evaluation PCB             |

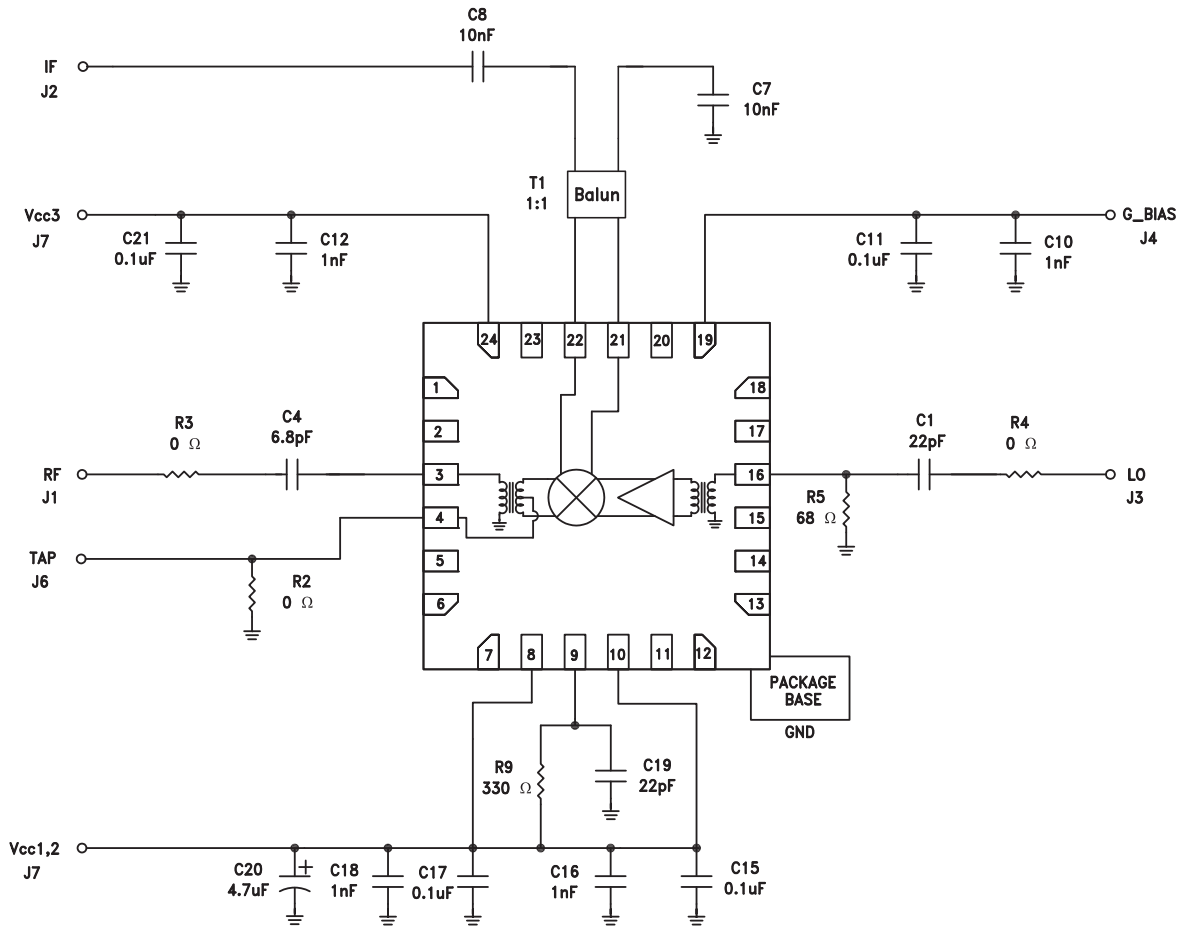
The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25R, FR4



**Application Circuit - 0.7 - 1.1 GHz RF Band**



10

MIXERS - SINGLE & DOUBLE BALANCED - SMT

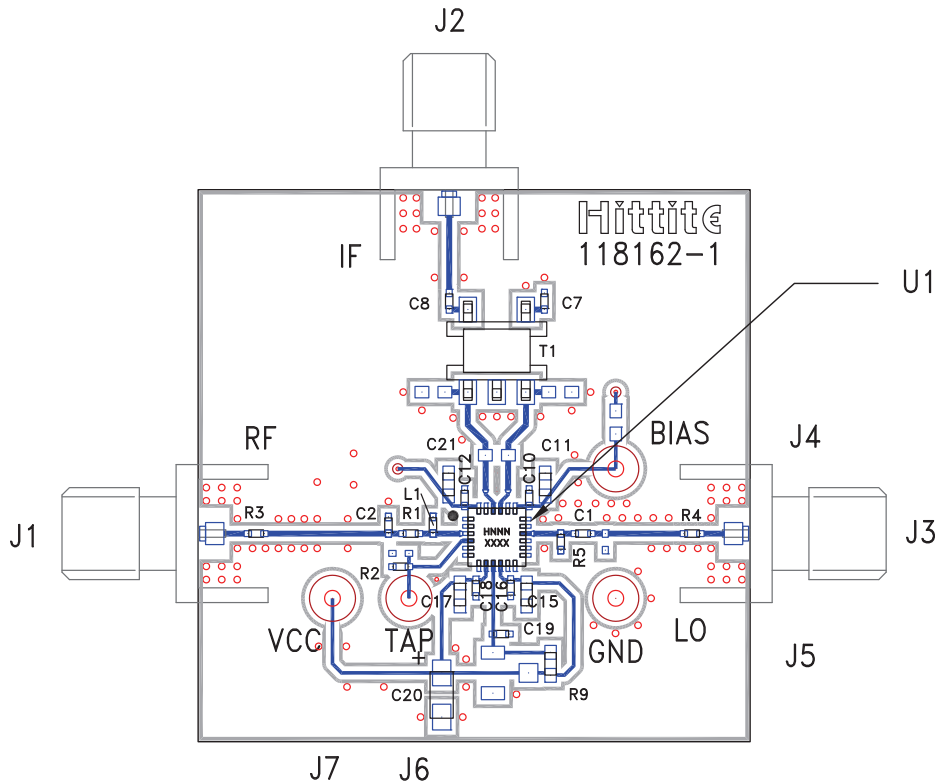
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D

**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**



**Evaluation PCB - 0.7 - 1.1 GHz RF Band, Narrowband High IP3 Upconverter Tune**



**List of Materials for Evaluation PCB 122410 [1]**

| Item               | Description                       |
|--------------------|-----------------------------------|
| J1 - J3            | SMA Connector                     |
| J4 - J7            | DC Pin                            |
| C1, C19            | 22 pF Capacitor, 0402 Pkg.        |
| C2                 | 4.7 pF Capacitor, 0402 Pkg.       |
| C7, C8             | 10 nF Capacitor, 0402 Pkg.        |
| C10, C12, C16, C18 | 1 nF Capacitor, 0402 Pkg.         |
| C11, C15, C17, C21 | 0.1 μF Capacitor, 0603 Pkg.       |
| C20                | 4.7 μF Case A, Tantalum           |
| R1                 | 0 Ohm Resistor, 0402 Pkg.         |
| R2 - R4            | 0 Ohm Resistor, 0402 Pkg.         |
| R5                 | 68 Ohm Resistor, 0402 Pkg.        |
| R9                 | 330 Ohm Resistor, 0603 Pkg.       |
| T1                 | 1:1 Transformer - Tyco MABACT0039 |
| U1                 | HMC686LP4(E) Downconverter        |
| L1                 | 5.6 nH Ind, 0402 Pkg.             |
| PCB [2]            | 118162 Evaluation PCB             |

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

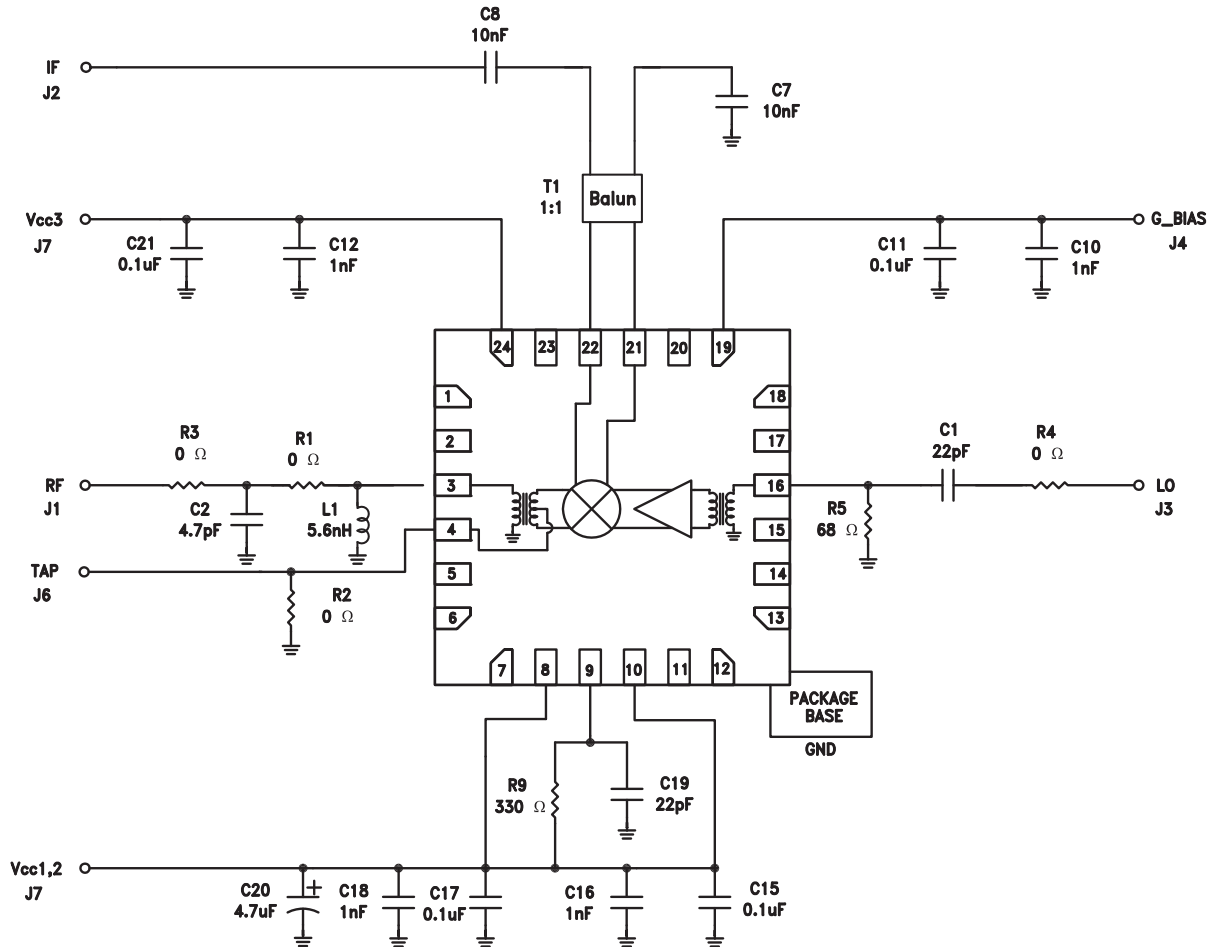
[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25R, FR4

**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**



**Application Circuit - 0.7 - 1.1 GHz RF Band, Narrowband High IP3 Upconverter Tune**



10

MIXERS - SINGLE & DOUBLE BALANCED - SMT

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

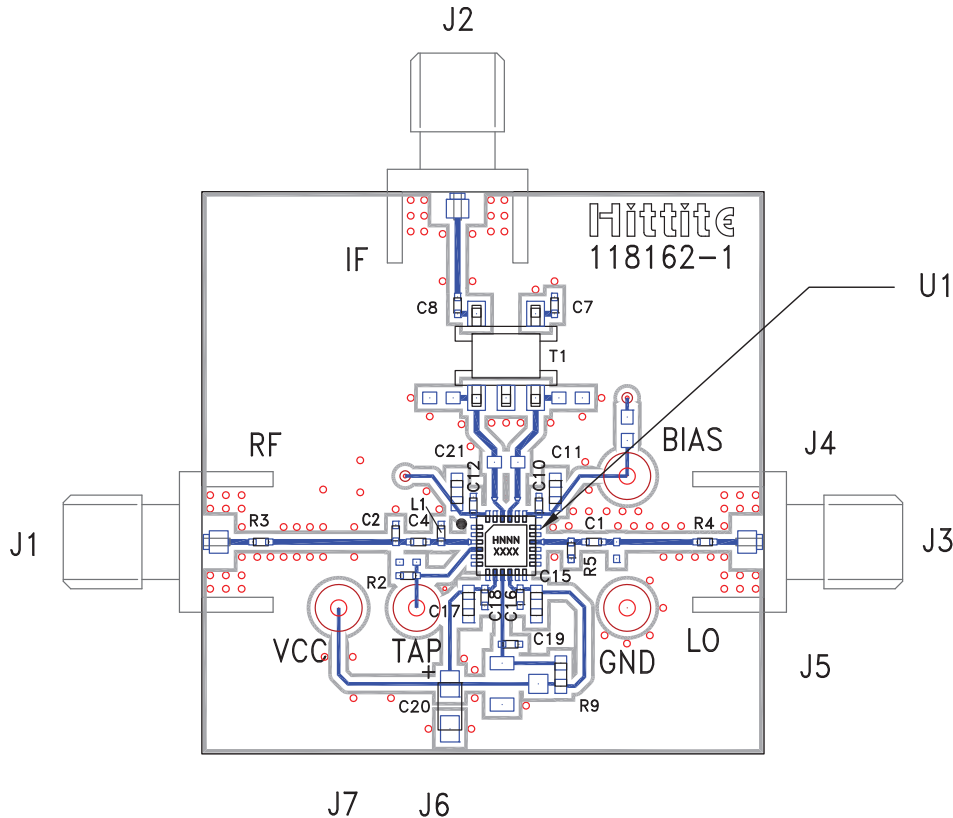
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**



**Evaluation PCB - 1.4 - 1.5 GHz RF LTE Band**



**List of Materials for Evaluation PCB 125658 [1]**

| Item               | Description                       |
|--------------------|-----------------------------------|
| J1 - J3            | SMA Connector                     |
| J4 - J7            | DC Pin                            |
| C1, C19            | 22 pF Capacitor, 0402 Pkg.        |
| C2                 | 2.2 pF Capacitor, 0402 Pkg.       |
| C4                 | 6.8 pF Capacitor, 0402 Pkg.       |
| C7, C8             | 10 nF Capacitor, 0402 Pkg.        |
| C10, C12, C16, C18 | 1 nF Capacitor, 0402 Pkg.         |
| C11, C15, C17, C21 | 0.1 μF Capacitor, 0603 Pkg.       |
| C20                | 4.7 μF Case A, Tantalum           |
| R2 - R4            | 0 Ohm Resistor, 0402 Pkg.         |
| R5                 | 68 Ohm Resistor, 0402 Pkg.        |
| R9                 | 270 Ohm Resistor, 0603 Pkg.       |
| T1                 | 1:1 Transformer - Tyco MABACT0039 |
| U1                 | HMC686LP4(E) Downconverter        |
| L1                 | 7.5 nH Ind, 0402 Pkg.             |
| PCB [2]            | 118162 Evaluation PCB             |

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

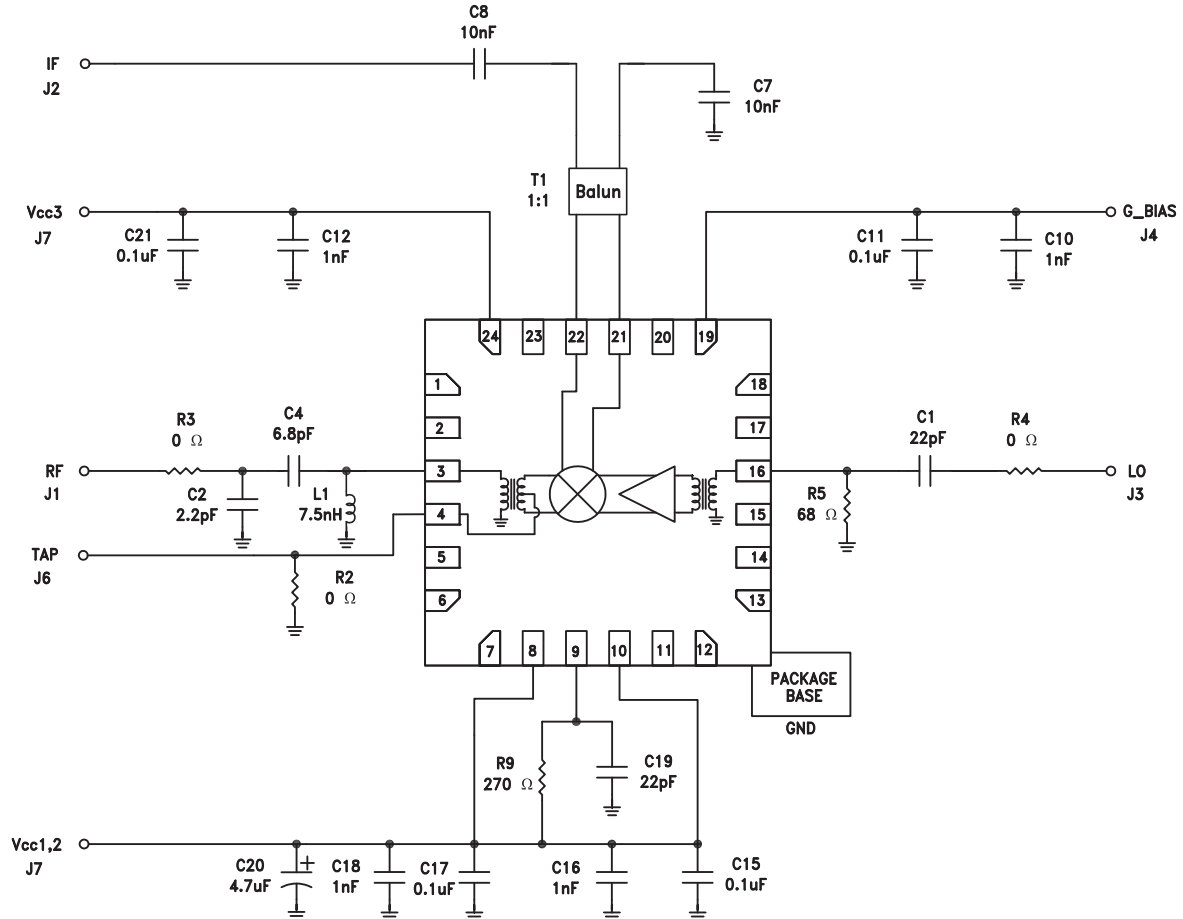
[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25R, FR4

**BiCMOS MIXER W/ INTEGRATED LO AMPLIFIER, 700 - 1500 MHz**



**Application Circuit - 1.4 - 1.5 GHz RF LTE Band**



10

MIXERS - SINGLE & DOUBLE BALANCED - SMT

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.